



100V PNP LOW VCESAT TRANSISTOR IN PowerDI3333-8

Features

- BV_{CEO} > -100V
- Small Form Factor Thermally Efficient Package.
 Enables Higher Density End Products
- I_C = -5A Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -100mV @ -1A
- $R_{SAT} = 60 \text{m}\Omega$ for a Low equivalent On-Resistance
- h_{FE} Specified up to -10A for a High Gain Hold-Up
- Complementary NPN Type: DXTN03100CFG
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

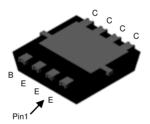
Applications

- Motor Driving
- Line Switching
- High Side Switches

PowerDI3333-8 (SWP) (Type UX)

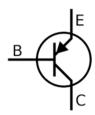


Top View



Bottom View

Equivalent Circuit



Device Symbol

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DXTP03100CFG-7	2K1	7	12	2,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2K1= Product Type Marking Code

YYWW = Date Code Marking

YY = Last Two Digits of Year (ex: 19 = 2019)

WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-110	V
Collector-Emitter Voltage	V_{CEO}	-100	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-5	Α
Peak Pulse Current	Ісм	-10	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1.07	W
Power Dissipation	(Note 6)	P _D	2.3	W
	(Note 7)		3.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8)		$R_{ heta JL}$	6	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +175	°C

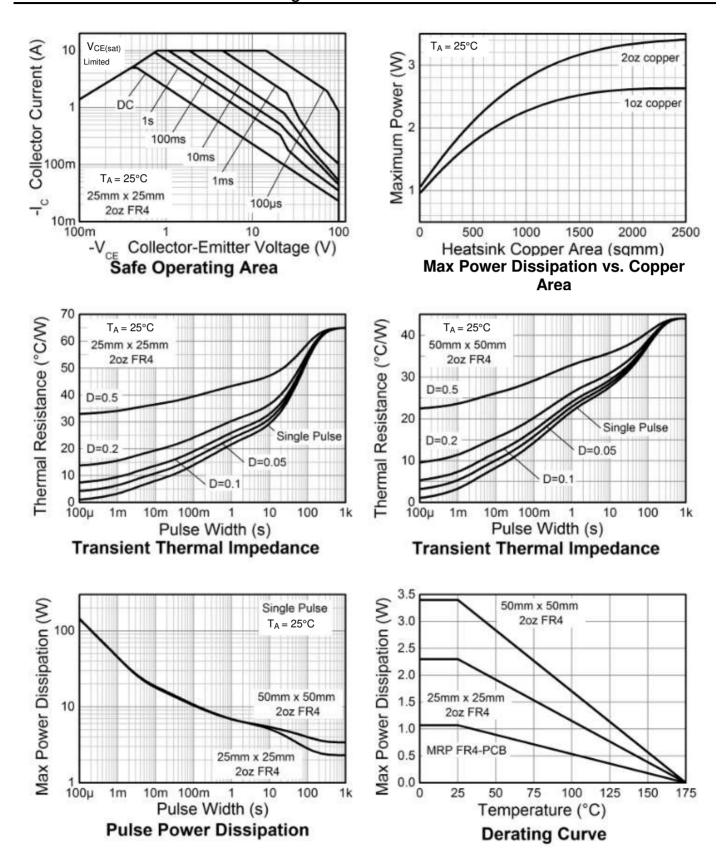
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class	
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A	
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С	

- 5. For a device mounted with the collector tab on MRP FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- For a device mounted with the collector tab on MRP FR-4 PLB; device is measted.
 Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
 Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
 Thermal resistance from junction to solder-point (at the collector tab).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





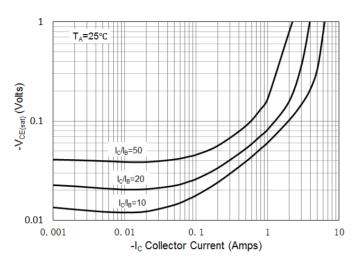
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

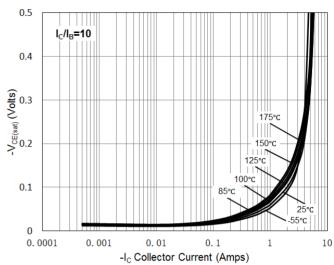
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-110	-138	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-100	-116	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.8	_	V	I _E = -100μA
Collector-Base Cut-Off Current	Ісво	_	-1	-50	nA	V _{CB} = -100V
Collector-base Cut-Oil Current		_	-0.07	10	μΑ	V _{CB} = -100V, T _A = +125°C
Collector Emitter Cut Off Current (B < 1kO)	I _{CER}	_	-2	-50	nA	V _{CB} = -100V
Collector-Emitter Cut-Off Current (R ≤ 1kΩ)		_	-2.3	50	μΑ	V _{CB} = -100V, T _A = +125°C
Emitter Cut-Off Current	I _{EBO}	_	-1	-20	nA	V _{EB} = -6V
		250	421	_	_	$I_C = -10 \text{mA}, V_{CE} = -2 \text{V}$
		200	338	800	_	I _C = -1A, V _{CE} = -2V
Static Forward Current Transfer Ratio (Note 10)	L	180	323	_	_	$I_C = -1.2A$, $V_{CE} = -2V$
Static Forward Current Transfer Hatto (Note 10)	h _{FE}	150	295	_	_	$I_C = -1.5A$, $V_{CE} = -2V$
		35	57	_	_	$I_{C} = -3A$, $V_{CE} = -2V$
		20	29	_	_	I _C = -4A, V _{CE} = -2V
	V _{CE(sat)}	_	-17.5	-40	mV	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
Collector-Emitter Saturation Voltage (Note 10)		_	-60	-100	mV	$I_C = -1A, I_B = -100mA$
Collector-Efflitter Saturation Voltage (Note 10)		_	-102	-180	mV	$I_C = -2A$, $I_B = -200mA$
		_	-212	-380	mV	$I_C = -4A$, $I_B = -400mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	_	-963	-1.1	mV	$I_C = -4A$, $I_B = -400$ mV
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	-888	-1	mV	$I_{C} = -4A, V_{CE} = -2V$
Output Capacitance	C _{obo}	_	42	_	pF	V _{CB} = -10V. f = 1MHz
Transition Frequency	f _T	_	125	_	MHz	$V_{CE} = -10V, I_{C} = -100mA$ f = 50MHz
	t _{delay}		6.8	_	ns	
Switching Characteristics	t _{rise}	_	259	_	ns	V _{CC} = -10V, I _C = -1A
Switching Characteristics	t _{storage}	_	1718	_	ns	$I_{B1} = -I_{B2} = -100 \text{mA}$
	t _{fall}		185	_	ns	

Note: 10. Measured under pulsed conditions. Pulse width \leqslant 300 μ s. Duty cycle \leqslant 2%.

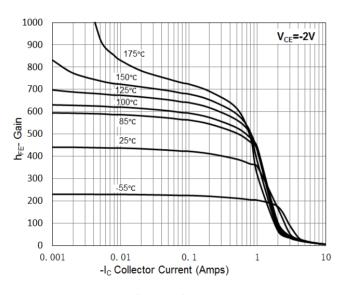


Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

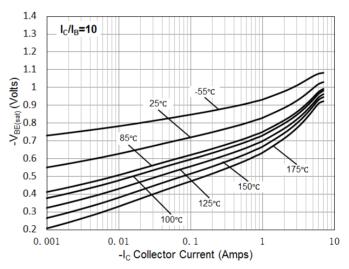


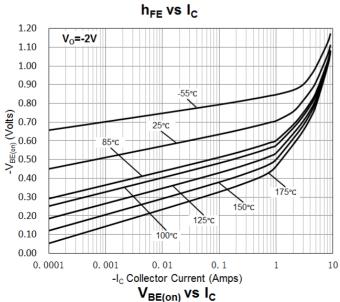


V_{CE(sat)}vs I_C



V_{CE(sat)}vs I_C





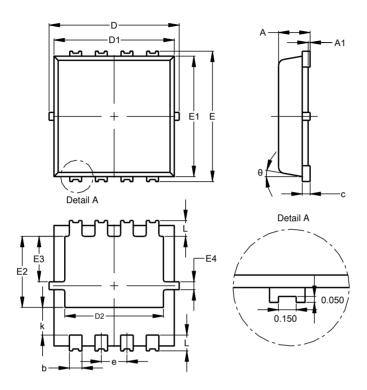
 $V_{\text{BE(sat)}} vs I_{\text{C}}$



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

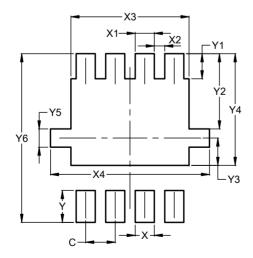


PowerDI3333-8 (SWP)					
(Type UX)					
Dim	Min Max		Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	-		
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е			0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)			
С	0.650			
Х	0.420			
X1	0.420			
X2	0.230			
Х3	2.600			
X4	3.500			
Υ	0.700			
Y1	0.550			
Y2	1.650			
Y3	0.600			
Y4	2.450			
Y5	0.400			
Y6	3.700			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.



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